Vishay Semiconductors

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eSMP[®] Series

Cathode O Anode

LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS							
I _{F(AV)} 2 A							
V _R	100 V						
V _F at I _F	0.72 V						
t _{rr}	25 ns						
T _J max.	175 °C						
Package	SlimSMA (DO-221AC)						
Circuit configuration	Single						

FEATURES

Hyperfast Rectifier, 2 A FRED Pt[®]

- Hyperfast recovery time, reduced Q_{rr}, and soft recovery
- 175 °C maximum operating junction temperature
- Low forward voltage drop
- Low leakage current
- Specific for output and snubber operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 $^{\circ}\mathrm{C}$
- Meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

State of the art hyperfast recovery rectifiers specifically designed with optimized performance of forward voltage drop and hyperfast recovery time.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in snubber, boost, lighting, as high frequency rectifiers and freewheeling diodes.

The extremely optimized stored charge and low recovery current minimize the switching losses and reduce power dissipation in the switching element.

MECHANICAL DATA

Case: SlimSMA (DO-221AC)

Molding compound meets UL 94 V-0 flammability rating

Terminals: matte tin plated leads, solderable per J-STD-002

Polarity: color band denotes cathode end

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Peak repetitive reverse voltage	V _{RRM}		100	V		
Average rectified forward current	I _{F(AV)}	$T_{\rm C} = 155 \ ^{\circ}{\rm C}^{(1)}$	2	٨		
Non-repetitive peak surge current	I _{FSM}	T _J = 25 °C	65	A		
Operating junction and storage temperatures	T _J , T _{Stg}		-65 to +175	°C		

Note

⁽¹⁾ Device on PCB with 8 mm x 16 mm soldering lands

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	V_{BR}, V_{R}	I _R = 100 μA	100	-	-		
Forward voltage	M	I _F = 2 A	-	0.85	0.93	V	
Forward voltage	V _F	I _F = 2 A, T _J = 125 °C	0.72	0.77			
Deveree leekege eurrent		$V_{R} = V_{R}$ rated	-	-	2		
Reverse leakage current	IR	$T_J = 125 \ ^{\circ}C, V_R = V_R \text{ rated}$	-	0.5	8	μA	
Junction capacitance	CT	V _R = 100 V	-	10	-	pF	

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RoHS

COMPLIANT HALOGEN

FREE



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DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS	
		$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 50 \text{ A}/\mu\text{s}, \text{ V}_R = 30 \text{ V}$		-	25	-	
Reverse recovery time	+	$I_F = 0.5 \text{ A}, I_R = 1 \text{ A}, I_R$	-	-	25		
Reverse recovery lime	t _{rr}	T _J = 25 °C		-	17	-	- ns - A
		T _J = 125 °C	I _F = 2 A dI _F /dt = 200 A/μs V _B = 160 V	-	24	-	
Deals receivers aurrent	I _{RRM}	T _J = 25 °C		-	2	-	
Peak recovery current		T _J = 125 °C		-	3	-	
	Q _{rr}	T _J = 25 °C		-	17	-	nC
Reverse recovery charge		T _J = 125 °C		-	37	-	nC

THERMAL - MECHANICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T _J , T _{Stg}		-65	-	175	°C
Thermal resistance, junction to mount		Device mounted on PCB with 8 mm x 16 mm soldering lands	-	-	12	°C/W
Thermal resistance, junction to ambient	R _{thJA}	Device mounted on PCB with 2 mm x 3.5 mm soldering lands	-	-	115	0/10
Approvimate weight			0.03		g	
Approximate weight				0.0011		oz.
Marking device Case style SlimSMA (I		Case style SlimSMA (DO-221AC)		21	H2	

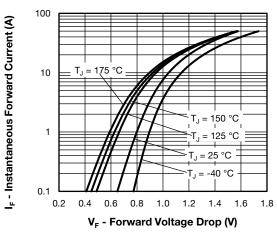


Fig. 1 - Typical Forward Voltage Drop Characteristics

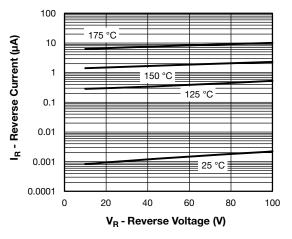
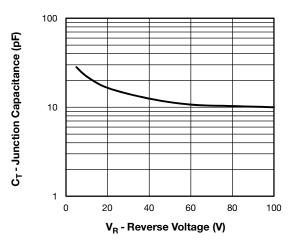


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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SHAY,

Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

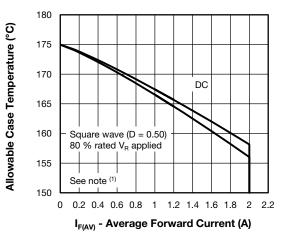


Fig. 4 - Maximum Allowable Case Temperature vs. Average Forward Current

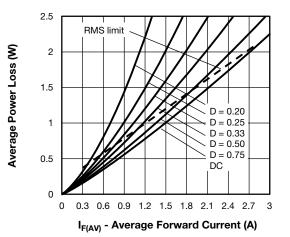


Fig. 5 - Forward Power Loss Characteristics

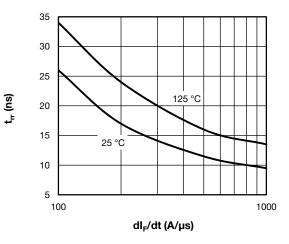


Fig. 6 - Typical Reverse Recovery Time vs. dI_F/dt

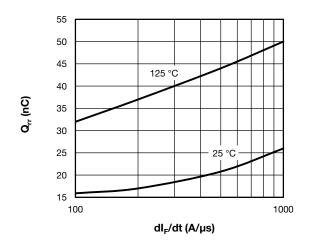


Fig. 7 - Typical Stored Charge vs. dl_F/dt

Note

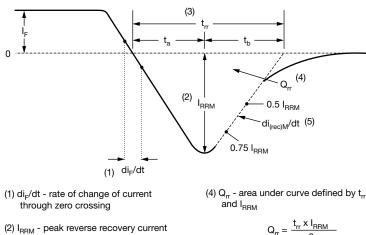
- ⁽¹⁾ Formula used: $T_C = T_J (Pd + Pd_{REV}) \times R_{thJC}$;
 - $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{Fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$

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(3) $t_{\rm rr}$ - reverse recovery time measured from zero crossing point of negative going $l_{\rm F}$ to point where a line passing through 0.75 I_{RRM} and 0.50 I_{RRM} extrapolated to zero current.

 $Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$

(5) di_{(rec)M}/dt - peak rate of change of current during t_b portion of t_{rr}

Fig. 8 - Reverse Recovery Waveform and Definitions

ORDERING INFORMATION TABLE

SHAY

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Device code

•	VS-		2	Е	J	н	01	-M3	
I	1		2	3	4	5	6	7	
	1	-		-	niconduc		oduct		
	2	-		Current rating (2 = 2 A) Circuit configuration:					
	4	-		= single diode = SlimSMA package					
	5	-		Process type, H = hyperfast recovery					
	6	-		•	le (01 =	,			
	7	-	-M3	= halog	jen-free	, RoHS-	-complia	ant, and	

ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER REEL	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-2EJH01-M3/6A	3500	3500	7"diameter plastic tape and reel				
VS-2EJH01-M3/6B	14 000	14 000	13"diameter plastic tape and reel				

LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95571				
Part marking information	www.vishay.com/doc?95562				
Packaging information	www.vishay.com/doc?88869				
SPICE model	www.vishay.com/doc?95634				

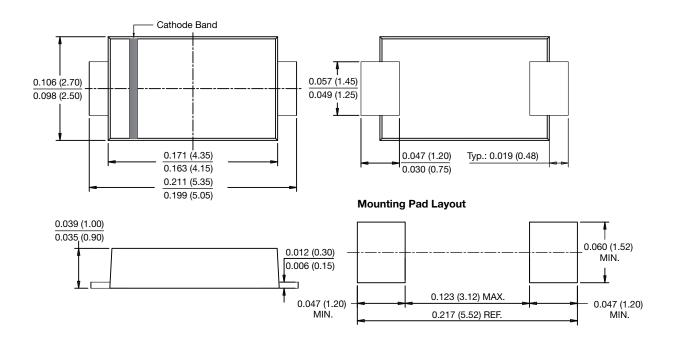
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DO-221AC (SlimSMA)

DIMENSIONS in inches (millimeters)





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